



FZT968

#### 12V PNP HIGH CURRENT LOW SATURATION POWER TRANSISTOR IN SOT223

#### **Features**

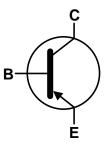
- BV<sub>CEO</sub> > -12V
- I<sub>C</sub> = -6A High Continuous Collector Current
- I<sub>CM</sub> = -20A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -170mV @ -2A</li>
- h<sub>FE</sub> Specified up to -10A for a High Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

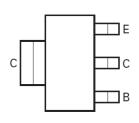
- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound.
   UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>3</sup>
- Weight: 0.112 grams (Approximate)







Device Symbol



Top View Pin-Out

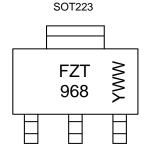
#### **Ordering Information** (Note 4)

ĺ	Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	FZT968TA	AEC-Q101	FZT968	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

# **Marking Information**



FZT 968 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01~53)



# Absolute Maximum Ratings ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-15	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-12	V
Emitter-Base Voltage	$V_{EBO}$	-6	V
Continuous Collector Current	lc	-6	Α
Peak Pulse Current	Ісм	-20	Α

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 6)	D.	3.0 24	W	
Linear derating factor	(Note 7)	P <sub>D</sub>	1.6 12.8	mW /°C	
Thermal Decistores, Junction to Ambient	(Note 6)	$R_{ heta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ heta JA}$	78	°C/W	
Thermal Resistance Junction to Lead (Note 8)		$R_{ heta JL}$	8.8		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

# ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

- 6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

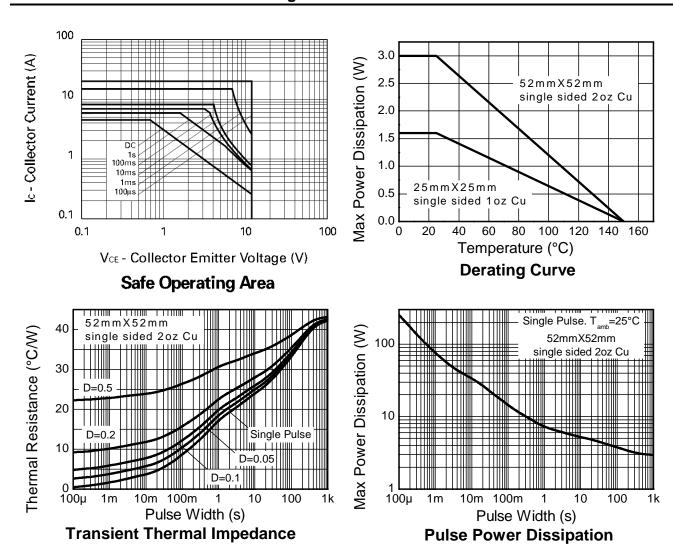
  7. Same as note (6), except the device is mounted on 25mm x 25mm 1oz copper.

  8. Thermal resistance from junction to solder-point (at the end of the collector lead).

  9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





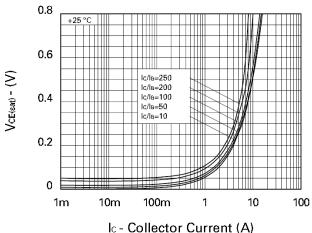
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-15	-28	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	-12	-20	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-6	-8	_	V	$I_E = -100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	_	<1 —	-10 -1	nA μA	V <sub>CB</sub> = -12V V <sub>CB</sub> = -12V, T <sub>A</sub> = +100°C
Emitter Cutoff Current	I <sub>EBO</sub>	_	<1	-10	nA	V <sub>EB</sub> = -6V
		300	450	_		$I_C = -10 \text{mA}, V_{CE} = -1 \text{V}$
	h <sub>FE</sub>	300	450	1,000		$I_C = -500 \text{mA}, V_{CE} = -1 \text{V}$
DC Current Transfer Static Ratio (Note 10)		200	300	_	_	$I_C = -5A$ , $V_{CE} = -1V$
		150	240	_		$I_C = -10A$ , $V_{CE} = -1V$
		_	50	_		$I_C = -20A$ , $V_{CE} = -1V$
	V <sub>CE(sat)</sub>	_	-65	-130	mV	$I_C = -500 \text{mA}, I_B = -5 \text{mA}$
Collector-Emitter Saturation Voltage (Note 10)		_	-132	-170		$I_C = -2A$ , $I_B = -50mA$
		_	-360	-450		$I_C = -6A$ , $I_B = -250mA$
Base-Emitter Saturation Voltage (Note 10)	$V_{BE(sat)}$	_	-1.05	-1.2	V	$I_C = -6A$ , $I_B = -250mA$
Base-Emitter Turn-on Voltage (Note 10)	$V_{BE(on)}$	_	-0.87	-1.05	V	$I_C = -6A$ , $V_{CE} = -1V$
Transitional Frequency (Note 10)	f⊤	_	80	_	MHz	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V, f = 50MHz
Output capacitance	C <sub>obo</sub>	_	161	_	pF	V <sub>CB</sub> = -20V, f = 1MHz
Switching Time	t <sub>ON</sub>	_	120	_	no	$V_{CC} = -10V, I_{C} = -4A,$
Switching Time	t <sub>OFF</sub>	_	116	_	ns	$I_{B1} = -I_{B2} = -400 \text{mA}$

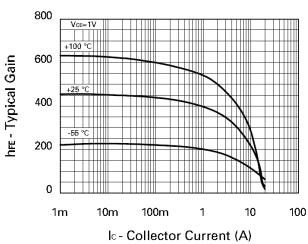
Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



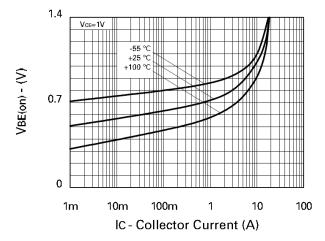
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



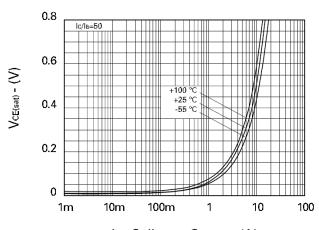
VCE(sat) v Ic



hfe v lc

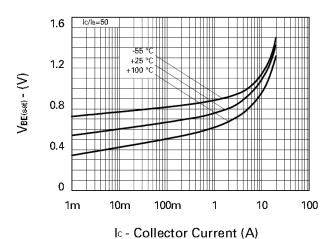


VBE(on) v lc



Ic - Collector Current (A)

#### VCE(sat) v Ic

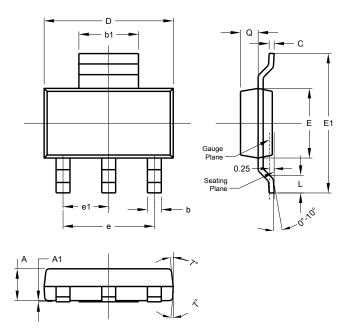


V<sub>BE(sat)</sub> v Ic



# **Package Outline Dimensions**

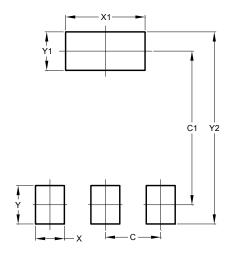
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223						
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
<b>e</b> 4.6						
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
C	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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